BLF542 UHF power MOS transistor Rev. 4 — 1 September 2015



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In data sheets, where the previous Philips references is mentioned, please use the new links as shown below.

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Thank you for your cooperation and understanding,

Ampleon

BLF542

FEATURES

- High power gain
- · Easy power control
- Good thermal stability
- Gold metallization ensures excellent reliability
- Withstands full load mismatch
- Designed for broadband operation.

APPLICATIONS

• Large signal amplifier applications in the UHF frequency range.

DESCRIPTION

N-channel enhancement mode vertical D-MOS power transistor encapsulated in a 6-lead, SOT171A flange package with a ceramic cap. All leads are isolated from the flange.

PINNING - SOT171A

PIN	DESCRIPTION			
1	source			
2	source			
3	gate			
4	drain			
5	source			
6	source			

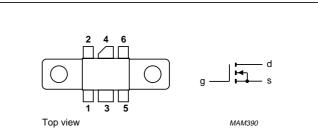


Fig.1 Simplified outline and symbol.

QUICK REFERENCE DATA

RF performance at T_h = 25 °C in a common source class-B circuit.

MODE OF OPERATION	f	V _{DS}	P _L	G _p	η _D
	(MHz)	(V)	(W)	(dB)	(%)
CW, class-B	500	28	5	>13	>50

CAUTION

This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling. For further information, refer to Philips specs.: SNW-EQ-608, SNW-FQ-302A and SNW-FQ-302B.

WARNING

Product and environmental safety - toxic materials

This product contains beryllium oxide. The product is entirely safe provided that the BeO disc is not damaged. All persons who handle, use or dispose of this product should be aware of its nature and of the necessary safety precautions. After use, dispose of as chemical or special waste according to the regulations applying at the location of the user. It must never be thrown out with the general or domestic waste.

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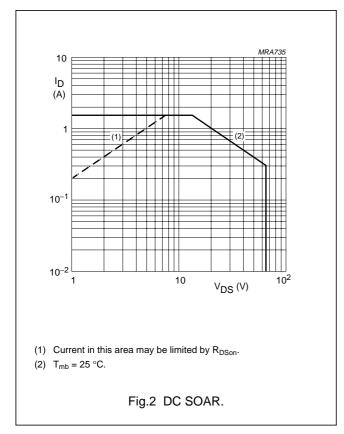
LIMITING VALUES

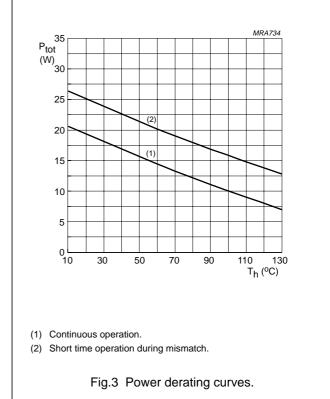
In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage		_	65	V
V _{GS}	gate-source voltage		-	±20	V
ID	drain current (DC)		-	1.5	А
P _{tot}	total power dissipation	T _{mb} = 25 °C	_	20	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	200	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-mb}	thermal resistance from junction to mounting base	8.8	K/W
R _{th mb-h}	thermal resistance from mounting base to heatsink	0.4	K/W





Product specification

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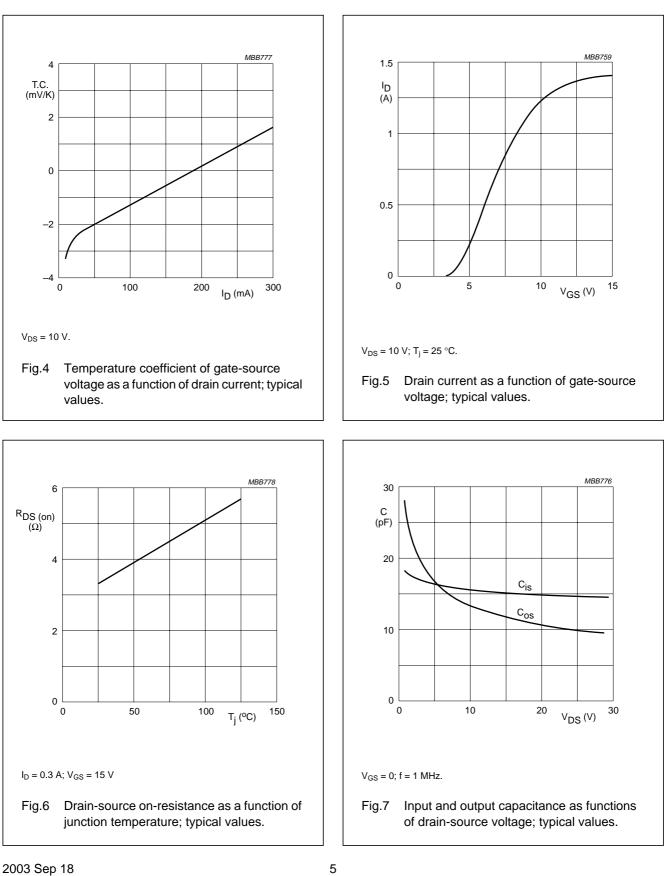
CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

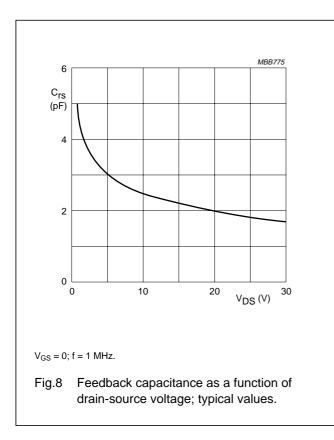
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 0.1 mA; V _{GS} = 0	65	-	-	V
I _{DSS}	drain-source leakage current	$V_{GS} = 0; V_{DS} = 28 V$	-	-	10	μA
I _{GSS}	gate-source leakage current	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0$	-	-	1	μA
V _{GSth}	gate-source threshold voltage	I _D = 10 mA; V _{DS} = 10 V	2	-	4.5	V
9 _{fs}	forward transconductance	I _D = 0.3 A; V _{DS} = 10 V	160	240	-	mS
R _{DSon}	drain-source on-resistance	$I_{D} = 0.3 \text{ A}; V_{GS} = 15 \text{ V}$	-	3.3	5	Ω
I _{DSX}	on-state drain current	V _{GS} = 15 V; V _{DS} = 10 V	-	1.4	-	A
C _{is}	input capacitance	V _{GS} = 0; V _{DS} = 28 V; f = 1 MHz	-	14	-	pF
C _{os}	output capacitance	V _{GS} = 0; V _{DS} = 28 V; f = 1 MHz	-	9.4	-	pF
C _{rs}	feedback capacitance	$V_{GS} = 0; V_{DS} = 28 V; f = 1 MHz$	-	1.7	-	pF

V_{GS} group indicator

GROUP	LIM (\		GROUP	LIMITS (V)		
	MIN.	MAX.		MIN.	MAX.	
A	2.0	2.1	0	3.3	3.4	
В	2.1	2.2	Р	3.4	3.5	
С	2.2	2.3	Q	3.5	3.6	
D	2.3	2.4	R	3.6	3.7	
E	2.4	2.5	S	3.7	3.8	
F	2.5	2.6	Т	3.8	3.9	
G	2.6	2.7	U	3.9	4.0	
Н	2.7	2.8	V	4.0	4.1	
J	2.8	2.9	W	4.1	4.2	
K	2.9	3.0	Х	4.2	4.3	
L	3.0	3.1	Y	4.3	4.4	
М	3.1	3.2	Z	4.4	4.5	
N	3.2	3.3				



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APPLICATION INFORMATION FOR CLASS-B OPERATION

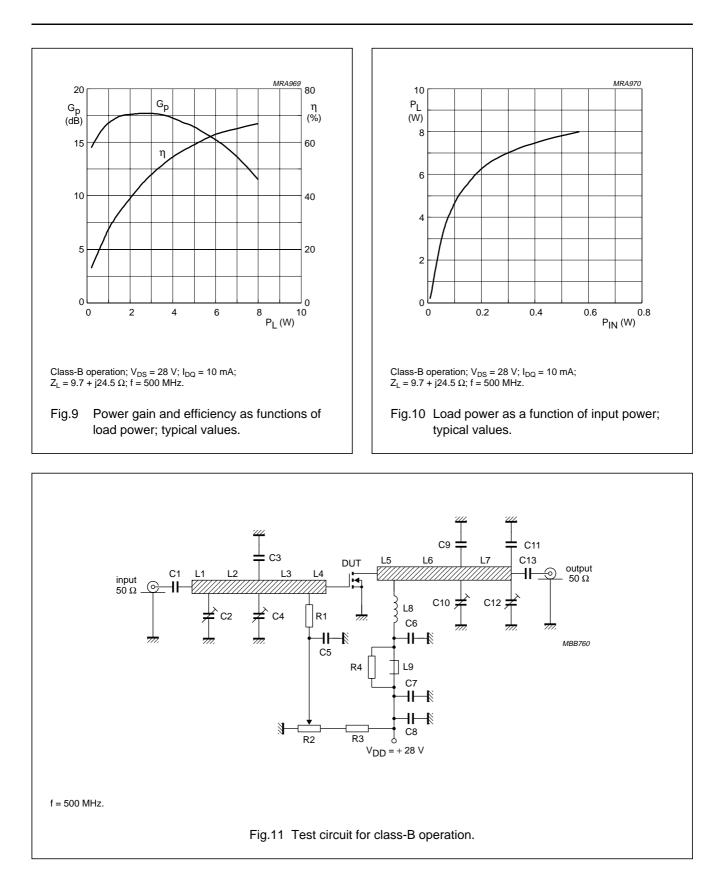
 T_{mb} = 25 °C unless otherwise specified.

RF performance in CW operation in a common source class-B test circuit.

MODE OF OPERATION	f	V _{DS}	I _{DQ}	P _L	G _P	η _D
	(MHz)	(V)	(mA)	(W)	(dB)	(%)
CW, class-B	500	28	50	5	>13 typ. 16.5	>50 typ. 59

Ruggedness in class-B operation

The BLF542 is capable of withstanding a full load mismatch corresponding to VSWR = 50:1 through all phases under the following conditions: V_{DS} = 28 V; f = 500 MHz at rated output power.



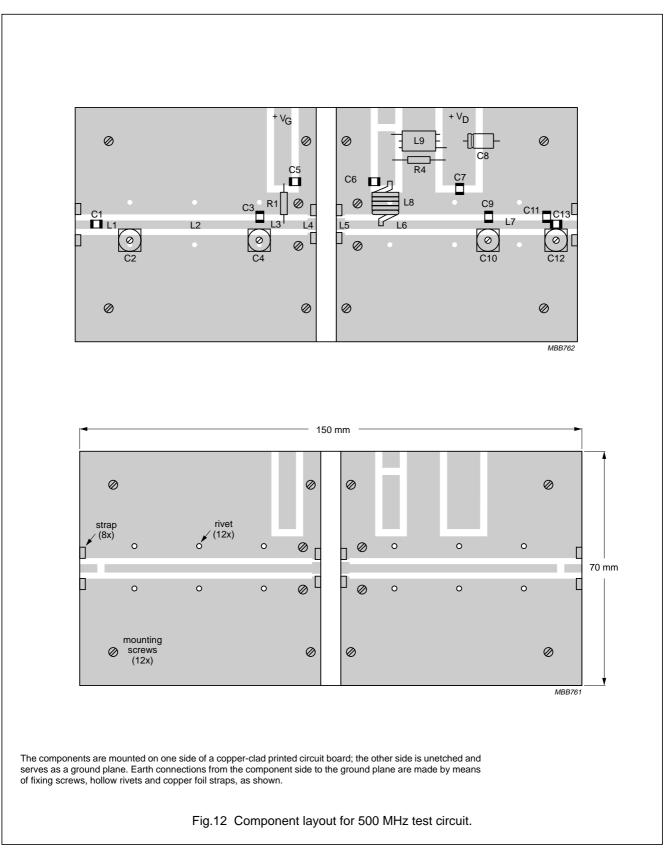
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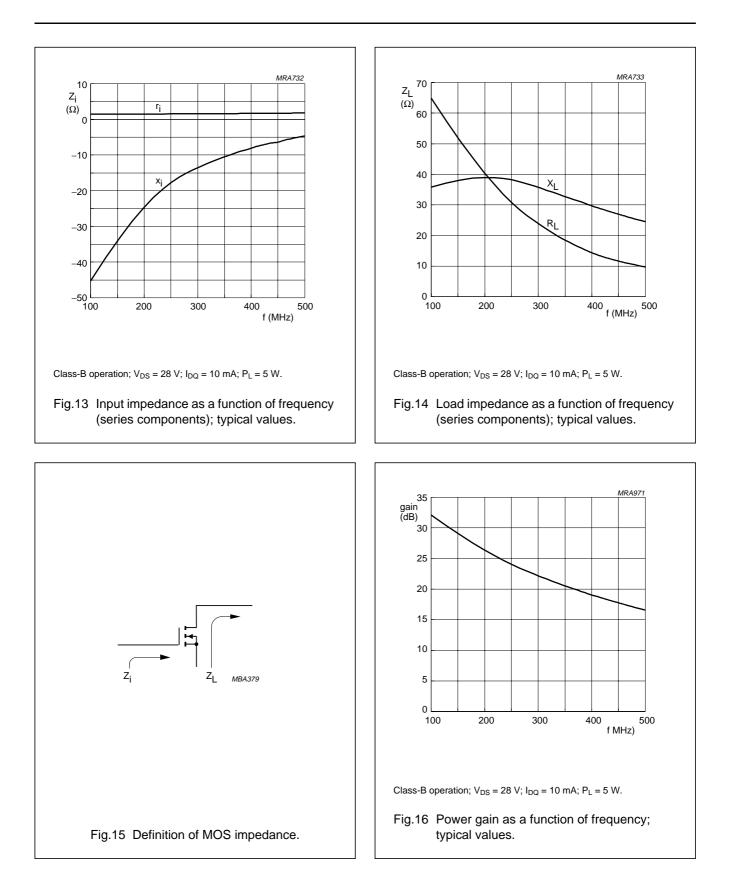
COMPONENT	DESCRIPTION	VALUE	DIMENSIONS	CATALOGUE NO.
C1, C5, C13	multilayer ceramic chip capacitor; note 1	390 pF		
C2, C4, C10, C12	film dielectric trimmer	2 to 18 pF		222 809 05217
C3, C9	multilayer ceramic chip capacitor; note 1	39 pF		
C6	multilayer ceramic chip capacitor; note 2	220 pF		
C7	multilayer ceramic chip capacitor	100 nF		2222 852 47104
C8	electrolytic capacitor	63 V, 10 μF		2222 030 28109
C11	multilayer ceramic chip capacitor; note 1	10 pF		
L1	stripline; note 3	50 Ω	$11 \text{ mm} \times 2.5 \text{ mm}$	
L2	stripline; note 3	50 Ω	$37 \text{ mm} \times 2.5 \text{ mm}$	
L3	stripline; note 3	50 Ω	$13 \text{ mm} \times 2.5 \text{ mm}$	
L4, L5	stripline; note 3	42 Ω	$3 \text{ mm} \times 3 \text{ mm}$	
L6	stripline; note 3	50 Ω	$39 \text{ mm} \times 2.5 \text{ mm}$	
L7	stripline; note 3	50 Ω	$22 \text{ mm} \times 2.5 \text{ mm}$	
L8	8 turns 0.8 mm enamelled copper wire	250 nH	length 9 mm int. dia. 6 mm leads 2×5 mm	
L9	grade 3B Ferroxcube wideband RF choke			4312 020 36640
R1	metal film resistor	10 kΩ, 0.4 W		2322 151 71003
R2	10 turn potentiometer	50 kΩ		
R3	metal film resistor	205 kΩ, 0.4 W		2322 151 72054
R4	metal film resistor	10 Ω, 0.4 W		2322 151 71009

List of components (see Fig.11)

Notes

- 1. American Technical Ceramics (ATC) capacitor, type 100A or other capacitor of the same quality.
- 2. American Technical Ceramics (ATC) capacitor, type 100B or other capacitor of the same quality.
- 3. The striplines are on a double copper-clad printed circuit board with PTFE fibre-glass dielectric (ϵ_r = 2.2); thickness 1_{32} inch.





BLF542

BLF542 scattering parameters

 V_{DS} = 28 V; I_D = 10 mA; note 1

f (MHz)		s ₁₁	S	21	S	12	s	22
((IVII 12)	s ₁₁	$\angle \Phi$	s ₂₁	$\angle \Phi$	s ₁₂	$\angle \Phi$	s ₂₂	$\angle \Phi$
5	1.00	-3.0	5.88	178.0	0.00	0.0	1.00	-2.3
10	1.00	-6.0	5.88	175.0	0.01	84.7	1.01	-6.0
20	1.00	-12.0	5.86	169.0	0.02	80.4	1.00	-11.0
30	0.99	-17.9	5.74	164.0	0.03	74.8	1.00	-17.2
40	0.98	-23.6	5.65	159.0	0.04	70.2	0.99	-22.4
50	0.98	-29.3	5.55	154.0	0.04	65.6	0.98	-27.3
60	0.97	-34.8	5.43	150.0	0.05	61.2	0.97	-32.1
70	0.96	-40.1	5.31	145.0	0.06	56.9	0.96	-36.8
80	0.94	-45.3	5.19	140.0	0.07	52.4	0.96	-41.8
90	0.93	-50.3	5.03	135.0	0.07	47.9	0.94	-46.9
100	0.92	-54.9	4.86	131.0	0.08	43.6	0.93	-51.6
125	0.89	-65.5	4.42	122.0	0.09	34.7	0.89	-61.6
150	0.87	-75.5	4.06	113.0	0.10	26.8	0.88	-70.0
175	0.85	-84.2	3.71	105.0	0.10	19.0	0.86	-78.2
200	0.83	-91.7	3.35	97.3	0.10	12.4	0.83	-85.3
250	0.82	-105.0	2.81	84.6	0.11	1.2	0.82	-96.8
300	0.81	-116.0	2.34	73.6	0.11	-8.6	0.81	-107.0
350	0.81	-125.0	2.00	64.0	0.10	-16.7	0.82	-115.0
400	0.81	-133.0	1.70	55.5	0.10	-23.8	0.82	-121.0
450	0.82	-140.0	1.48	47.7	0.09	-30.2	0.83	-128.0
500	0.83	-146.0	1.28	40.9	0.09	-35.6	0.84	-133.0
600	0.86	-157.0	1.00	29.0	0.08	-44.9	0.87	-142.0
700	0.87	-166.0	0.79	18.6	0.07	-52.3	0.89	-149.0
800	0.89	-175.0	0.64	9.8	0.06	-58.1	0.90	-155.0
900	0.90	178.0	0.53	2.0	0.05	-62.4	0.92	-160.0
1000	0.91	171.0	0.45	-4.8	0.04	-64.9	0.93	-165.0

Note

1. For more extensive s-parameters see internet:

http://www.semiconductors.philips.com/markets/communications/wirelesscommunication/broadcast.

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BLF542 scattering parameters

f (MHz)	s ₁₁		S	21	S	12	S ₂₂		
	s ₁₁	$\angle \Phi$	s ₂₁	$\angle \Phi$	s ₁₂	$\angle \Phi$	s ₂₂	$\angle \Phi$	
5	1.00	-4.1	12.20	177.0	0.00	0.0	0.99	-3.2	
10	1.00	-8.2	12.20	173.0	0.01	83.5	1.00	-7.8	
20	0.99	-16.3	12.10	167.0	0.02	78.1	0.99	-14.5	
30	0.98	-24.1	11.70	161.0	0.03	71.7	0.98	-22.3	
40	0.97	-31.7	11.40	155.0	0.03	66.2	0.96	-28.8	
50	0.95	-39.1	11.10	150.0	0.04	60.9	0.94	-35.1	
60	0.93	-46.1	10.70	144.0	0.05	55.8	0.93	-41.1	
70	0.92	-52.7	10.30	139.0	0.06	51.1	0.91	-46.8	
80	0.90	-59.1	9.92	134.0	0.06	46.2	0.89	-52.7	
90	0.88	-65.1	9.47	129.0	0.07	41.6	0.87	-58.4	
100	0.86	-70.3	9.00	125.0	0.07	37.3	0.85	-63.6	
125	0.82	-81.9	7.95	116.0	0.08	28.7	0.80	-74.1	
150	0.80	-92.5	7.12	107.0	0.08	21.2	0.78	-82.8	
175	0.77	-101.0	6.37	99.9	0.08	14.2	0.75	-90.7	
200	0.75	-109.0	5.68	93.5	0.08	8.5	0.73	-97.4	
250	0.74	-121.0	4.67	82.4	0.09	-1.3	0.72	-108.0	
300	0.73	-130.0	3.87	72.9	0.08	-9.4	0.71	-116.0	
350	0.74	-138.0	3.29	64.5	0.08	-16.3	0.72	-123.0	
400	0.75	-145.0	2.81	57.2	0.08	-22.2	0.73	-129.0	
450	0.76	-151.0	2.44	50.3	0.07	-27.7	0.74	-134.0	
500	0.77	-156.0	2.13	44.2	0.07	-32.2	0.75	-138.0	
600	0.79	-165.0	1.67	33.3	0.06	-40.0	0.79	-145.0	
700	0.82	-173.0	1.34	23.6	0.05	-46.1	0.82	-152.0	
800	0.84	180.0	1.10	15.2	0.04	-50.4	0.85	-157.0	
900	0.86	173.0	0.92	7.5	0.04	-52.9	0.87	-162.0	
1000	0.87	167.0	0.78	0.7	0.03	-52.8	0.88	-166.0	

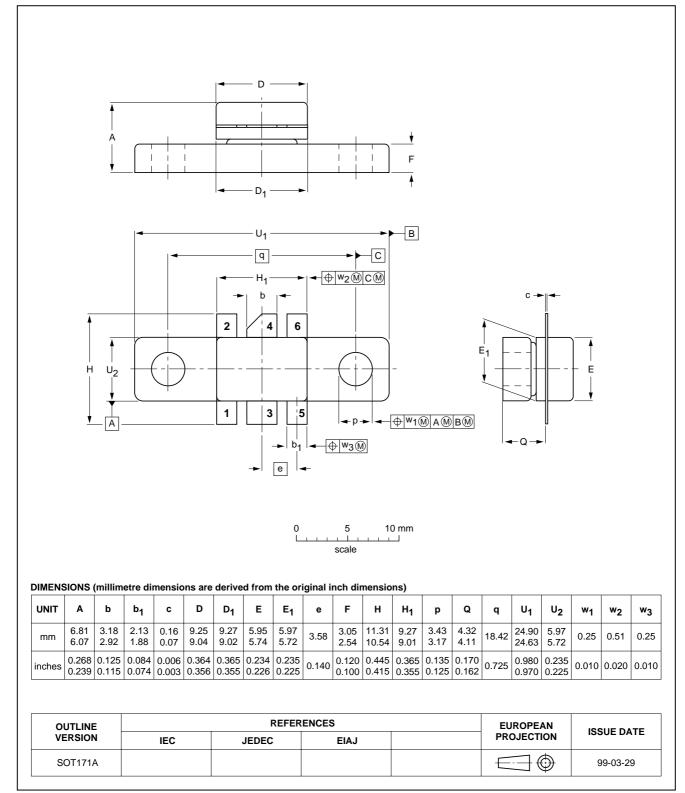
Note

1. For more extensive s-parameters see internet:

http://www.semiconductors.philips.com/markets/communications/wirelesscommunication/broadcast.

PACKAGE OUTLINE

Flanged ceramic package; 2 mounting holes; 6 leads



BLF542

SOT171A

Product specification

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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